



SEMI®
International
Standards



SEMI® International Standards Program

Compound Semiconductor Technical Committee Meeting

Teleconference Meeting

Wed 18th April 2018

13:00 to 14:30

V2 23.03.2018

Co-chairs:

- [Dr. Arnd-Dietrich Weber, SiCrystal](#)
- [N.N.](#)

Agenda

European Compound Semiconductor Committee Meeting (Teleconference)

13:00	Welcome and Self-Introductions	all
13:05	SEMI Standards Overview and Legal Reminders	SEMI Staff
13:10	Review of the minutes and action items from the previous meeting	SEMI Staff
13:15	Task Force Reports (~5 minutes each) <ul style="list-style-type: none"> • Contactless Capacitive Resistivity Task Force • 5y-review M54 (Guide for semi-insulating GaAs parameters) • SiC-Task Force 	W. Jantz U. Kretzer A. Weber
13:35	Discuss upcoming 5-year-review of M82 and M83 (GaAs carbon acceptor concentration by IR spectroscopy), M83 (EPD test method for III-V materials)	all
14:00	Compound Materials Liaison Reports <ul style="list-style-type: none"> • North America • Japan 	SEMI Staff
14:10	Any Other Business / Questions	A. Weber
14:20	Next Meeting (Proposal: SEMICON Europa 2018, Munich)	all
14:30	Adjourn	